Product data sheet

## 1. Product profile

## 1.1 General description

Planar PIN diode in a SOD523 ultra small plastic SMD package.

### 1.2 Features and benefits

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Very low series inductance
- For applications up to 6 GHz
- AEC-Q101 qualified

## 1.3 Applications

RF attenuators and switches

# 2. Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	cathode [1]		14
2	anode	1 2	sym006

<sup>[1]</sup> The marking bar indicates the cathode.

# 3. Ordering information

Table 2. Ordering information

Type number	Package					
	Name	Description	Version			
BAP64-02	-	plastic surface-mounted package; 2 leads	SOD523			



Silicon PIN diode

# 4. Marking

Table 3. Marking

Type number	Marking code
BAP64-02	S

# 5. Limiting values

### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit		
$V_R$	reverse voltage		-	175	V		
I <sub>F</sub>	forward current		-	100	mA		
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 90 °C	-	715	mW		
T <sub>stg</sub>	storage temperature		-65	+150	°C		
Tj	junction temperature		-65	+150	°C		

## 6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		85	K/W

## 7. Characteristics

### Table 6. Characteristics

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 50 mA	-	0.95	1.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 175 V	-	-	10	μΑ
		V <sub>R</sub> = 20 V	-	-	1	μΑ
C <sub>d</sub> diode capacitance		see Figure 1; f = 1 MHz;				
		V <sub>R</sub> = 0 V	-	0.48	-	pF
		V <sub>R</sub> = 1 V	-	0.35	-	pF
		V <sub>R</sub> = 20 V	-	0.23	0.35	pF

Silicon PIN diode

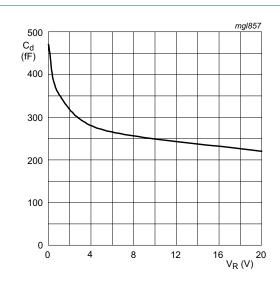
 Table 6.
 Characteristics ...continued

 $T_i = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
r <sub>D</sub>	diode forward resistance	see <u>Figure 2</u> ; f = 100 MHz; [1]				
		I <sub>F</sub> = 0.5 mA	-	20	40	Ω
		I <sub>F</sub> = 1 mA	-	10	20	Ω
		I <sub>F</sub> = 10 mA	-	2.0	3.8	Ω
		I <sub>F</sub> = 100 mA	-	0.7	1.35	Ω
τ∟	charge carrier life time	when switched from I <sub>F</sub> = 10 mA to I <sub>R</sub> = 6 mA; R <sub>L</sub> = 100 $\Omega$ ; measured at I <sub>R</sub> = 3 mA	-	1.55	-	μѕ
L <sub>S</sub>	series inductance		-	0.6	-	nΗ

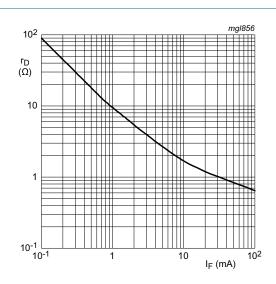
<sup>[1]</sup> Guaranteed on AQL basis: inspection level S4, AQL 1.0.

Silicon PIN diode



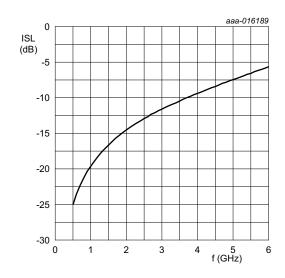
f = 1 MHz;  $T_i = 25 \, ^{\circ}\text{C}$ .

Fig 1. Diode capacitance as a function of reverse voltage; typical values



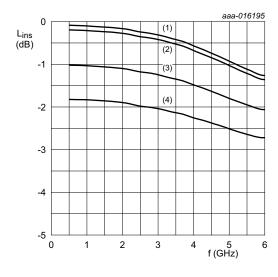
f = 100 MHz;  $T_j$  = 25 °C.

Fig 2. Forward resistance as a function of forward current; typical values



T<sub>amb</sub> = 25 °C

Diode zero biased and inserted in series with a 50  $\Omega$  stripline circuit



T<sub>amb</sub> = 25 °C

- (1)  $I_F = 100 \text{ mA}$
- (2)  $I_F = 10 \text{ mA}$
- (3)  $I_F = 1 \text{ mA}$
- (4)  $I_F = 0.5 \text{ mA}$

Diode inserted in series with a 50  $\Omega$  stripline circuit and biased via the analyzer Tee network

Fig 4. Insertion loss of the diode as a function of frequency; typical values

Fig 3. Isolation of the diode as a function of frequency; typical values

Silicon PIN diode

# 8. Package outline

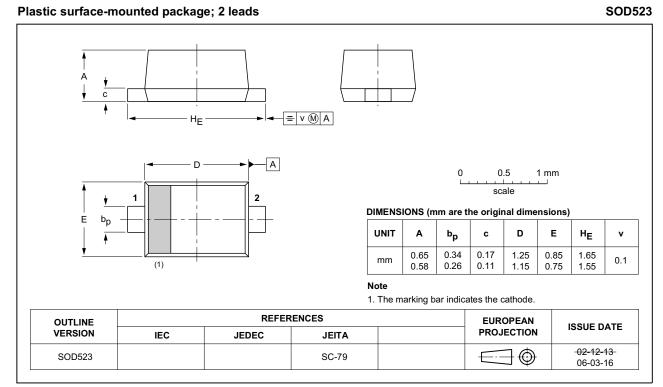


Fig 5. Package outline SOD523

## 9. Abbreviations

Table 7. Abbreviations

Acronym	Description
AQL	Acceptable Quality Level
PIN	P-type, Intrinsic, N-type
SMD	Surface Mounted Device
S4	Special inspection level 4

Silicon PIN diode

# 10. Revision history

## Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP64-02 v.10	20150512	Product data sheet	-	BAP64-02 v.9
Modifications:	• AEC-Q101 d	qualified		
BAP64-02 v.9	20141215	Product data sheet	-	BAP64-02 v.8
BAP64-02 v.8	20140428	Product data sheet	-	BAP64-02 v.7
BAP64-02 v.7	20140211	Product data sheet	-	BAP64-02_N v.6
BAP64-02_N v.6	20080109	Product data sheet	-	BAP64-02 v.5
BAP64-02 v.5 (9397 750 06912)	20000323	Product specification	-	BAP64-02 v.4
BAP64-02 v.4 (9397 750 06418)	19990921	Preliminary specification	-	BAP64-02_N v.3
BAP64-02_N v.3 (9397 750 06086)	19990616	Preliminary specification	-	BAP64-02 v.2
BAP64-02 v.2 (9397 750 05556)	19990510	Objective specification	-	BAP64-02_N v.1
BAP64-02_N v.1 (9397 750 05492)	19981204	Objective specification	-	-

Silicon PIN diode

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#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BAP64-02

#### Silicon PIN diode

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## Silicon PIN diode

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